3.3V Differential In 1:10 Differential Fanout Clock Driver with HCSL Level Output

Description

The NB4N111K is a differential input clock 1 to 10 HCSL fanout buffer, optimized for ultra low propagation delay variation. The NB4N111K is designed with HCSL clock distribution for FBDIMM applications in mind.

Inputs can accept differential LVPECL, CML, or LVDS levels. Single–ended LVPECL, CML, LVCMOS or LVTTL levels are accepted with the proper V_{REFAC} supply (see Figures 5, 10, 11, 12, and 13). Clock input pins incorporate an internal 50 Ω on die termination resistors.

The NB4N111K specifically guarantees low output-to-output skews. Optimal design, layout, and processing minimize skew within a device and from device to device. System designers can take advantage of the NB4N111K's performance to distribute low skew clocks across the backplane or the motherboard.

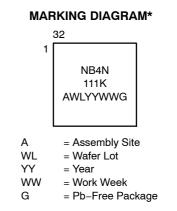
Features

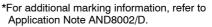
- Typical Input Clock Frequencies: 100, 133, 166, 200, 266, 333, and 400 MHz
- 340 ps Typical Rise and Fall Times
- 800 ps Typical Propagation Delay
- Δtpd 100 ps Maximum Propagation Delay Variation Per Each Differential Pair
- <1 ps RMS Additive Clock jitter
- Operating Range: $V_{CC} = 3.0 \text{ V}$ to 3.6 V with $V_{EE} = 0 \text{ V}$
- Differential HCSL Output Level
- These are Pb–Free Devices

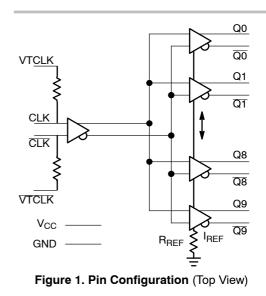


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ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

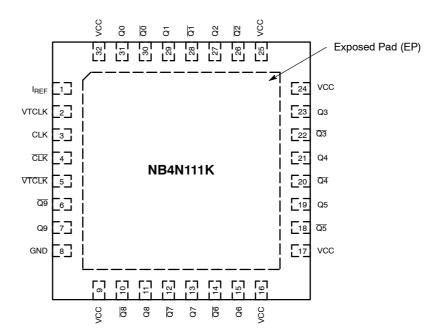




Table 1. PIN DESCRIPTION

Pin	Name	I/O	Description
1	I _{REF}	Output	Output current programming pin. Connect to GND. (See Figure 9).
2, 5	VTCLK, VTCLK	-	Internal 50 Ω Termination Resistor connection Pins. In the differential configuration when the input termination pins are connected to the common termination voltage, and if no signal is applied then the device may be susceptible to self-oscillation.
3	CLK	LVPECL Input	CLOCK Input (TRUE)
4	CLK	LVPECL Input	CLOCK Input (INVERT)
8	GND	-	Supply Ground. GND pin must be externally connected to power supply to guarantee proper operation.
9, 16, 17, 24, 25, 32	V _{CC}	-	Positive Supply pins. V_{CC} pins must be externally connected to a power supply to guarantee proper operation.
6, 10, 12, 14, 18, 20, 22, 26, 28, 30	Q[09–0]	HCSL Output	Output (INVERT)
7, 11, 13, 15, 19, 21, 23, 27, 29, 31	Q[09–0]	HCSL Output	Output (TRUE)
Exposed Pad	EP	GND	Exposed Pad. The thermally exposed pad (EP) on package bottom (see case drawing) must be attached to a sufficient heat-sinking conduit for proper thermal operation. (Note 1)

1. The exposed pad must be connected to the circuit board ground.

Table 2. ATTRIBUTES

Characteristic	Value	
Input Default State Resistors	None	
ESD Protection	Human Body Model	>2 kV
Moisture Sensitivity (Note 2)	QFN32	Level 1
Flammability Rating Oxygen Index: 28 to	UL 94 V-0 @ 0.125 in	
Transistor Count	622	
Meets or exceeds JEDEC Spec EIA/JES		

2. For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS (Note 3)

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	Positive Power Supply	GND = 0 V		6	V
VI	Positive Input	GND = 0 V		$GND - 0.3 \leq V_{I} \leq V_{CC}$	V
V _{INPP}	Differential Input Voltage CLK - CLK			1.2	V
I _{OUT}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range	QFN32		-40 to +70	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient) (Note 3)	0 lfpm 500 lfpm	QFN32 QFN32	31 27	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	2S2P (Note 4)	QFN32	12	°C/W
T _{sol}	Wave Solder Pb-Free			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
3. JEDEC standard 51–6, multilayer board – 2S2P (2 signal, 2 power).
4. JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

Table 4. DC CHARACTERISTICS (V_{CC} = 3.0 V to 3.6 V, T_A = -40° C to $+70^{\circ}$ C Note 5)

Symbol	Characteristic	Min	Тур	Max	Unit
I _{GND}	GND Supply Current (All Outputs Loaded)	70	98	120	mA
I _{CC}	Power Supply Current (All Outputs Loaded)			300	mA
I _{IH}	Input HIGH Current CLKx, CLKx		2.0	150	μA
IIL	Input LOW Current CLKx, CLKx	–150	-2.0		μA
DIFFERE	NTIAL INPUT DRIVEN SINGLE-ENDED (Figures 5 and 7)				
V _{th}	Input Threshold Reference Voltage Range (Note 6)	1050		V _{CC} – 150	mV
V _{IH}	Single-Ended Input HIGH Voltage	V _{th} + 150		V _{CC}	mV
V _{IL}	Single-Ended Input LOW Voltage	GND		V _{th} – 150	mV
DIFFERE	NTIAL INPUTS DRIVEN DIFFERENTIALLY (Figures 6 and 8)				
V _{IHD}	Differential Input HIGH Voltage	1200		V _{CC}	mV
V _{ILD}	Differential Input LOW Voltage	GND		V _{CC} – 75	mV
V _{ID}	Differential Input Voltage (V _{IHD} – V _{ILD})	75		2400	mV
V _{CMR}	Input Common Mode Range	1163		V _{CC} – 75	
HCSL OL	JTPUTS (Figure 4)	•	•	•	
V _{OH}	Output HIGH Voltage	600	740	900	mV

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

-150

0

150

mV

5. Input parameters vary 1:1 with V_{CC}. Measurements taken with all outputs loaded 50 Ω to GND, see Figure 9.

6. V_{th} is applied to the complementary input when operating in single ended mode.

V_{OL}

Output LOW Voltage

Symbol	Characteristic		Min	Тур	Max	Unit
V _{OUTPP}	Output Voltage Amplitude (@ V _{INPPmin}) f _{in} = 4	400 MHz		725	1000	mV
t _{PLH} , t _{PHL}	Propagation Delay to (See Figure 3) CLK/CLK t	o Qx/ Qx	550	800	1100	ps
Δt_{PLH} , Δt_{PHL}	Propagation Delay Variations Variation Per Each Diff Pair CLK/CLK to Qx/Qx (See Figure 3)	(Note 8)			100	ps
t _{SKEW}	Duty Cycle Skew (Note 9) Within-Device Skew Device-to-Device Skew (Note 10)				20 100 150	ps ps ps
t _{JITTER}	RMS Random Clock Jitter (Note 11) f _{in} = 4	400 MHz			1	ps
V _{INPP}	Input Voltage Swing/Sensitivity (Differential Configuration)		150		1200	mV
V _{cross}	Absolute Crossing Magnitude Voltage		250		550	mV
ΔV_{cross}	Variation in Magnitude of V _{cross}				150	mV
t _r , t _f	Absolute Magnitude in Output Risetime and Falltime (From 175 mV to 525 mV)	Qx, Qx	175	340	700	ps
$\Delta t_{r,} \Delta t_{f}$	Variation in Magnitude of Risetime and Falltime (Single-Ended) (See Figure 4)	Qx, Qx			125	ps

Table 5. AC CHARACTERISTICS V_{CC} = 3.0 V to 3.6 V, GND = 0 V; -40°C to +70°C (Note 7)

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

 Measured by forcing V_{INPP} (MIN) from a 50% duty cycle clock source. Measurements taken with all outputs loaded 50 Ω to GND, see Figure 9. Typical gain is 20 dB.

Measured from the input pair crosspoint to each single output pair crosspoint across temp and voltage ranges.

9. Duty cycle skew is measured between differential outputs using the deviations of the sum of Tpw- and Tpw+.

10. Skew is measured between outputs under identical transition @ 400 MHz.

11. Additive RMS jitter with 50% duty cycle clock signal using phase noise integrated from 12 KHz to 33 MHz

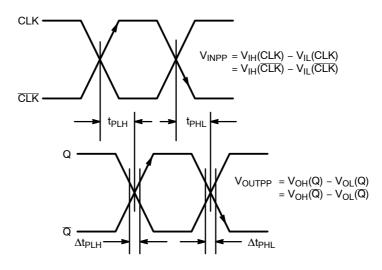


Figure 3. AC Reference Measurement

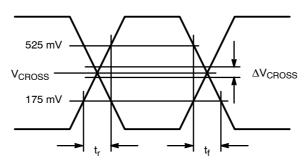
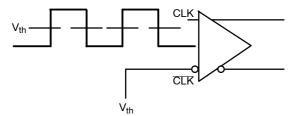
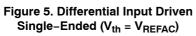
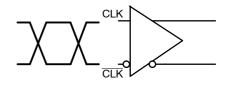
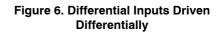


Figure 4. HCSL Output Parameter Characteristics









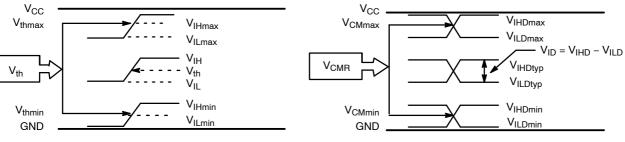
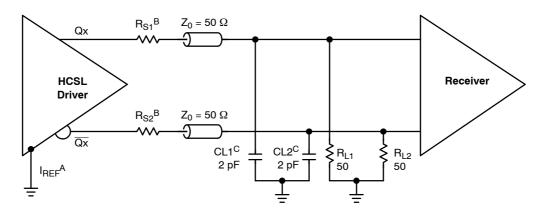
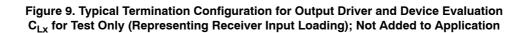


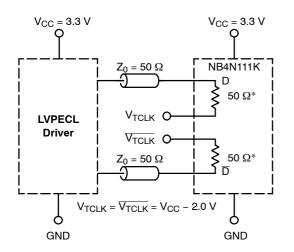
Figure 7. V_{th} Diagram

Figure 8. V_{CMR} Diagram



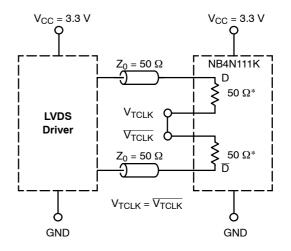
A. Connect $_{IREF}$ pin to GND. B. RS1, RS2: 0 Ω for Test and Evaluation. Select to Minimizing Ringing. C. CL1, CL2: Receiver Input Simulation Load Capacitance Only.





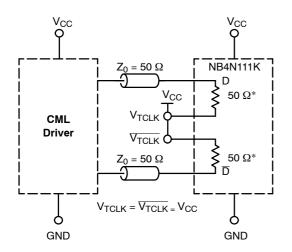
*RTIN, Internal Input Termination Resistor

Figure 10. LVPECL Interface

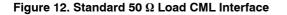


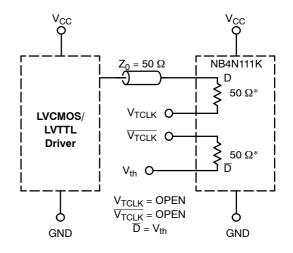
*RTIN, Internal Input Termination Resistor

Figure 11. LVDS Interface



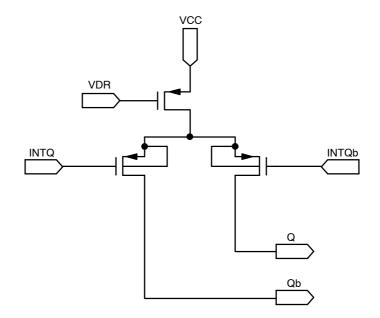
*RTIN, Internal Input Termination Resistor





*RTIN, Internal Input Termination Resistor

Figure 13. LVCMOS/LVTTL Interface





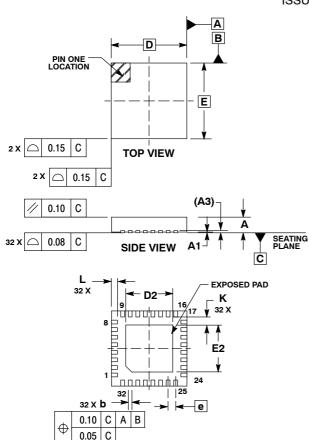
ORDERING INFORMATION

Device	Package	Shipping [†]
NB4N111KMNG	QFN32 (Pb-Free)	79 Units / Rail
NB4N111KMNR4G	QFN32 (Pb-Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

QFN32 5x5, 0.5P CASE 488AM-01 ISSUE O



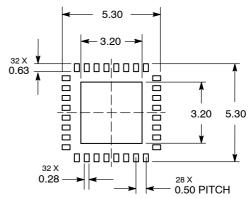
BOTTOM VIEW

NOTES:

- 1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM TERMINAL
- 0.25 AND 0.30 MM TERMINAL 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.800	0.900	1.000	
A1	0.000	0.025	0.050	
A3	0.200 REF			
b	0.180	0.250	0.300	
D	5.	.00 BSC		
D2	2.950	3.100	3.250	
Е	5.	.00 BSC		
E2	2.950	3.100	3.250	
e	0.500 BSC			
К	0.200			
L	0.300	0.400	0.500	

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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